# NPN General Purpose Transistor

The MMBT2222AM3T5G device is a spin-off of our popular SOT-23 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-723 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

#### **Features**

- Reduces Board Space
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit	
Collector - Emitter Voltage	V <sub>CEO</sub>	40	Vdc	
Collector - Base Voltage	V <sub>CBO</sub>	75	Vdc	
Emitter – Base Voltage	V <sub>EBO</sub>	6.0	Vdc	
Collector Current – Continuous	Ic	600	mAdc	

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	265 2.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	470	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	640 5.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	195	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

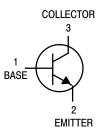
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.



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## MARKING DIAGRAM

SOT-723 CASE 631AA STYLE 1



AA M Specific Device CodeDate Code

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MMBT2222AM3T5G	SOT-723 (Pb-Free)	8000/Tape & Reel
NSVMMBT2222AM3T5G	SOT-723 (Pb-Free)	8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25$ °C unless otherwise noted)

Character	istic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 10	) mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	40	_	Vdc
Collector – Base Breakdown Voltage ( $I_C = 10 \mu$	Adc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	75	_	Vdc
Emitter – Base Breakdown Voltage ( $I_E = 10 \mu A$	dc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	6.0	_	Vdc
Collector Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB(of</sub>	<sub>(f)</sub> = 3.0 Vdc)	I <sub>CEX</sub>	-	10	nAdc
Collector Cutoff Current		I <sub>CBO</sub>	_ _	0.01 10	μAdc
Emitter Cutoff Current ( $V_{EB} = 3.0 \text{ Vdc}$ , $I_{C} = 0$ )		I <sub>EBO</sub>	-	100	nAdc
Base Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB(off)</sub> =	3.0 Vdc)	I <sub>BL</sub>	-	20	nAdc
ON CHARACTERISTICS					
$\begin{array}{l} \text{DC Current Gain} \\ (I_C = 0.1 \text{ mAdc, V}_{CE} = 10 \text{ Vdc}) \\ (I_C = 1.0 \text{ mAdc, V}_{CE} = 10 \text{ Vdc}) \\ (I_C = 10 \text{ mAdc, V}_{CE} = 10 \text{ Vdc}) \\ (I_C = 10 \text{ mAdc, V}_{CE} = 10 \text{ Vdc}) \\ (I_C = 10 \text{ mAdc, V}_{CE} = 10 \text{ Vdc}) \\ (I_C = 150 \text{ mAdc, V}_{CE} = 10 \text{ Vdc}) \\ (I_C = 150 \text{ mAdc, V}_{CE} = 1.0 \text{ Vdc}) \\ (I_C = 500 \text{ mAdc, V}_{CE} = 10 \text{ Vdc}) \\ (Notice = 10$	te 3)	hFE	35 50 75 35 100 50 40	- - - 300 - -	-
	V <sub>CE(sat)</sub>	_ _	0.3 1.0	Vdc	
$\begin{aligned} \text{Base-Emitter Saturation Voltage (Note 3)} \\ \text{(I}_{\text{C}} &= 150 \text{ mAdc, I}_{\text{B}} = 15 \text{ mAdc)} \\ \text{(I}_{\text{C}} &= 500 \text{ mAdc, I}_{\text{B}} = 50 \text{ mAdc)} \end{aligned}$	V <sub>BE(sat)</sub>	0.6 -	1.2 2.0	Vdc	
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (Note 4) (I <sub>C</sub> = 20 mAdc, V <sub>CE</sub> = 20 Vdc, f = 100 MHz)		f⊤	300	_	MHz
Output Capacitance ( $V_{CB} = 10 \text{ Vdc}$ , $I_E = 0$ , $f =$	C <sub>obo</sub>	-	8.0	pF	
Input Capacitance (V <sub>EB</sub> = 0.5 Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)		C <sub>ibo</sub>	-	25	pF
Input Impedance $ \begin{aligned} &(I_C=1.0 \text{ mAdc, V}_{CE}=10 \text{ Vdc, f}=1.0 \text{ kHz}) \\ &(I_C=10 \text{ mAdc, V}_{CE}=10 \text{ Vdc, f}=1.0 \text{ kHz}) \end{aligned} $		h <sub>ie</sub>	2.0 0.25	8.0 1.25	kΩ
Voltage Feedback Ratio $ \begin{array}{l} \text{(I}_{\text{C}} = 1.0 \text{ mAdc, V}_{\text{CE}} = 10 \text{ Vdc, f} = 1.0 \text{ kHz)} \\ \text{(I}_{\text{C}} = 10 \text{ mAdc, V}_{\text{CE}} = 10 \text{ Vdc, f} = 1.0 \text{ kHz)} \end{array} $		h <sub>re</sub>	_ _	8.0 4.0	X 10 <sup>-4</sup>
Small – Signal Current Gain ( $I_C$ = 1.0 mAdc, $V_{CE}$ = 10 Vdc, f = 1.0 kHz) ( $I_C$ = 10 mAdc, $V_{CE}$ = 10 Vdc, f = 1.0 kHz)		h <sub>fe</sub>	50 75	300 375	-
Output Admittance $ \begin{aligned} &(I_C=1.0 \text{ mAdc, V}_{CE}=10 \text{ Vdc, f}=1.0 \text{ kHz}) \\ &(I_C=10 \text{ mAdc, V}_{CE}=10 \text{ Vdc, f}=1.0 \text{ kHz}) \end{aligned} $		h <sub>oe</sub>	5.0 25	35 200	μmhos
Collector Base Time Constant (I <sub>E</sub> = 20 mAdc, V <sub>CB</sub> = 20 Vdc, f = 31.8 MHz)		rb, C <sub>c</sub>	_	150	ps
Noise Figure (I <sub>C</sub> = 100 $\mu$ Adc, V <sub>CE</sub> = 10 Vdc, R <sub>S</sub> = 1.0 k $\Omega$ , f = 1.0 kHz)		NF	_	4.0	dB
SWITCHING CHARACTERISTICS					
Delay Time	$(V_{CC} = 30 \text{ Vdc}, V_{BE(off)} = -0.5 \text{ Vdc},$	t <sub>d</sub>	-	10	ns
Rise Time	$I_C = 150 \text{ mAdc}, I_{B1} = 15 \text{ mAdc})$	t <sub>r</sub>	-	25	
Storage Time	$(V_{CC} = 30 \text{ Vdc}, I_{C} = 150 \text{ mAdc},$	t <sub>S</sub>	_	225	ns
Fall Time	$I_{B1} = I_{B2} = 15 \text{ mAdc}$		_	60	113

<sup>3.</sup> Pulse Test: Pulse Width  $\leq 300~\mu s$ , Duty Cycle  $\leq 2.0\%$ . 4.  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

## **SWITCHING TIME EQUIVALENT TEST CIRCUITS**

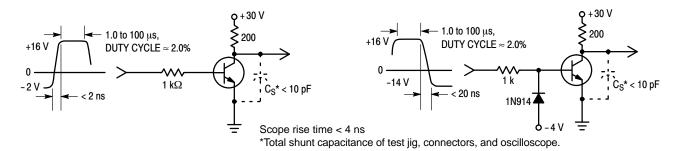


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

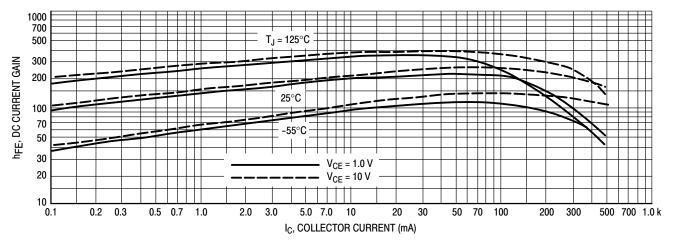


Figure 3. DC Current Gain

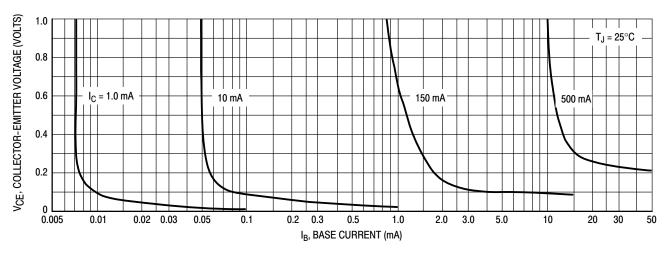


Figure 4. Collector Saturation Region

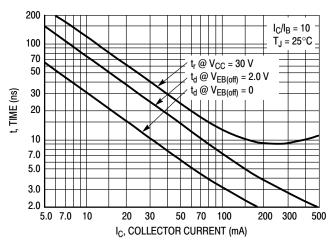


Figure 5. Turn-On Time

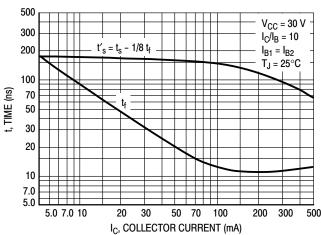


Figure 6. Turn-Off Time

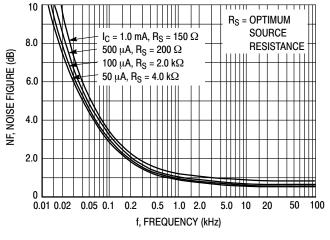


Figure 7. Frequency Effects

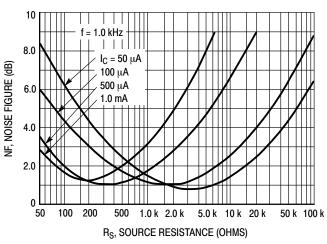


Figure 8. Source Resistance Effects

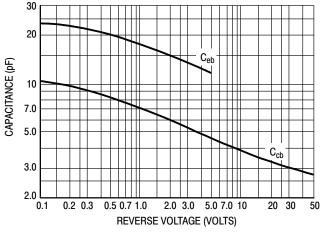


Figure 9. Capacitances

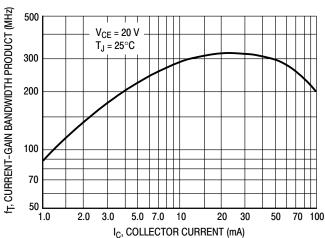
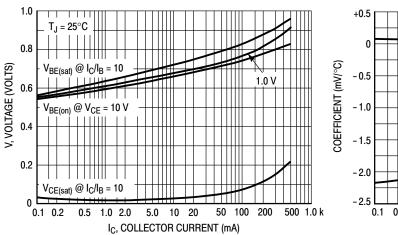
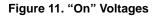
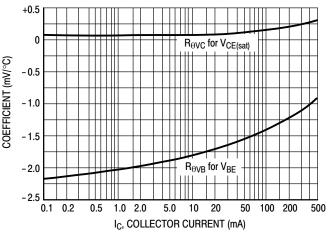


Figure 10. Current-Gain Bandwidth Product



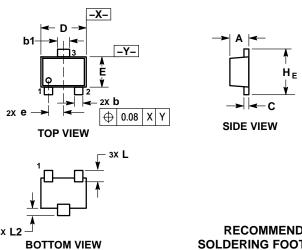




**Figure 12. Temperature Coefficients** 

#### PACKAGE DIMENSIONS

#### SOT-723 CASE 631AA ISSUE D



#### NOTES

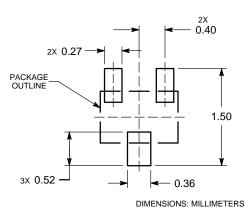
- 1. DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS

	MILLIMETERS		
DIM	MIN	NOM	MAX
Α	0.45	0.50	0.55
b	0.15	0.21	0.27
b1	0.25	0.31	0.37
С	0.07	0.12	0.17
D	1.15	1.20	1.25
E	0.75	0.80	0.85
е	0.40 BSC		
ΗE	1.15	1.20	1.25
L	0.29 REF		
L2	0.15	0.20	0.25

STYLE 1:

PIN 1. BASE 2. EMITTER 3. COLLECTOR

## **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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